NIRMA UNIVERSITY SCHOOL OF TECHNOLOGY, INSTITUTE OF TECHNOLOGY M.Tech. in Electronics & Communication Engineering (VLSI Design) M.Tech. Semester - II

Department Elective I

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Course Code	6EC164ME22
Course Title	CMOS RF Circuit Design

Course Learning Outcomes (CLOs):

At the end of the course, students will be able to -

- 1. Evaluate receiver architectures based on the RF performance parameters.
- 2. Analyse high frequency MOS based circuits working under Linear or Saturation Region.
- 3. Design and implement RF integrated circuits using active and passive components for given specifications.

Syllabus: Teaching Hou	rs:45
UNIT I: Introduction and Transmission Media Introduction and applications of RF systems. RF systems – Basic architectures, Transmission media and reflections, Maximum power transfer.	04
UNIT II: RF Concepts	05
Smith Charts, Two Port networks, Noise, Non-linearity, Sensitivity and Dynamic Range. UNIT III: RLC Circuits using MOS	04
Matching networks basics, Pi network, T network, RL, RC and RLC matching circuits, Fabrication of passive Devices using MOS.	
UNIT VI: Noise	04
Types of noises, Noise in MOSFETs, Noise modelling for CMOS, Intrinsic MOS noise parameters, Noise figure.	
UNIT V: LNA and Mixer	09
Power match versus noise match, Large signal performance, Mixer basics, single balanced mixers, double balanced mixers.	
UNIT VI: RF Power Amplifiers	06
Class A, AB, B, C amplifiers, Class D, E, F amplifiers.	
UNIT VII: Phase Lock Loops, Oscillators and Frequency Synthesizers	13
Linearized PLL models, Phase detectors, charge pumps, Loop filters, Resonators, Negative resistance, Oscillators, Frequency division, Integer-N synthesis, Fractional frequency synthesis, NCO and DDS	

Self-Study:

The self-study contents will be declared at the commencement of Semester. Around 10% of the questions will be asked from self-study contents.

Suggested Readings:

- 1. Thomas H. Lee, The Design of CMOS Radio-Frequency Integrated Circuits, Cambridge University Press
- 2. Behzad Razavi, RF Microelectronics, Prentice Hall of India
- 3. Bosco Lenug, VLSI for Wireless Communication, Prentice Hall of India
- 4. Robert Caverly, CMOS RF IC Design Principles, Artech House.
- 5. M. Jamal Deen, Tor A. Fjeldly, CMOS RF Modelling characterization and application, World Scientific Publication